Entrapment of magnetic microcrystals for on-chip electron spin resonance studies

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On-chip electron spin resonance (ESR) of magnetic molecules requires the ability to precisely position nanosized samples in antinodes of the electromagnetic field for maximal magnetic interaction. A method is developed to entrap microcrystals containing spins in a well defined location on a substrate's surface. Traditional cavity ESR measurements are then performed on a mesoscopic crystal at 34 GHz. Polycrystalline diluted Cr⁵⁺ spins are entrapped as well and measured while approaching the lower limit of the ESR sensitivity. This method suggests the feasibility of on-chip ESR measurements at dilution refrigerator temperatures by enabling the positioning of samples atop an on-chip superconducting cavity. © 2009 American Institute of Physics.

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Research performed over the past years in the area of quantum information has made significant theoretical and experimental advances toward the realization of practical quantum computers. The basic operational unit, the qubit, is realized in two- or few-level quantum systems, and several possibilities are currently being explored. Proposed qubits span the field of quantum physics from atoms in rare gases to solid-state systems, the latter being the preferred candidates for building future quantum chips. In addition to a viable qubit, it is necessary to have a method to read out the quantum state of the qubit. Devices based on resonance techniques have gained a significant momentum in the recent years (e.g., Refs. 1 and 2) and have been applied to readout superconducting qubits. Such methods should be adjustable to sense spin qubits or, more generally, to study basic phenomena in quantum magnetism, as proven by first approaches based on superconducting quantum interference device³ and Hall^{4,5} techniques.

For the purpose of spin-based quantum computing, molecular magnets are an attractive candidate due to their wellstudied quantum properties. 6-8 Synthesized in crystalline nanostructures, the magnetic molecules have a well defined size, shape, and orientation, allowing an accurate characterization of their quantum mechanical parameters. Moreover, some molecules, with a high spin ground state and high magnetic anisotropy, show tunable quantum phenomena via tunable tunneling channels through a large zero-field energy barrier. 9,10,5 In terms of coherence times, other diluted spin systems have been proven to be even closer to the requirements of a quantum computer, as shown in systems such as nitrogen in C₆₀ (Ref. 11) and the nitrogen-vacancy (NV) color centers. 12,13 Additionally, recent measurements of coherence in magnetic ions diluted in a crystal matrix have demonstrated single and multiphoton Rabi oscillations at low temperature ¹⁴ and up to room temperature. ^{15,16}

An experimental challenge, particularly applicable to spin qubits due to their nanosized dimensions, is related to the controlled positioning of the spins in an area that can be read out by the output electronics. In this paper we address this issue and introduce an experimental method allowing the placement of nanosized samples in well defined locations of a chip. In addition, to show that the spins' environment is not altered by the chemical procedures, we perform traditional cavity electronic spin resonance (ESR) measurements on samples containing a sufficiently large amount of spins detectable by a 34 GHz Q-band setup. The entrapping method is applied to the well-known ESR calibration standard 1,3bisdiphenylene-2 phenylallyl (BDPA) and to K₃NbO₈ nanocrystals containing diluted magnetic ions of Cr^{5+} (S=1/2). Note that the method can be extended to molecular nanomagnets as well. In the case of diluted Cr5+ spins in a K₃NbO₈ lattice, decoherence is due only to superhyperfine interactions in the neighboring K and Nb atoms, where there are no electronic spins. ^{15,17} This diluted Cr system is also quasi-isotropic, making it an ideal candidate for on-chip applications and an excellent demonstration for the method proposed here.

Placement of magnetic microcrystals requires the ability to nondestructively deposit crystals without introducing contaminants that would potentially interfere with the measurements. The method developed for microcrystal placement makes use of standard photolithography techniques as a means for defining the placement region (see Fig. 1). Microcrystals are first ground into a powder and then placed on a clean substrate surface using precision tip tweezers near the region where crystals are desired. It is important to stress that it is necessary for the crystals to be in direct contact with the surface prior to applying photoresist because the crystals can act as a mask themselves. In such situations, an undeveloped photoresist may act as an adhesion layer preventing the re-

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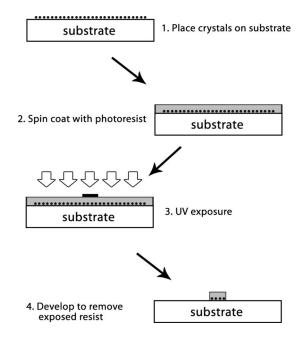


FIG. 1. Graphic representation of the entrapment technique developed for microcrystal placement. The substrate is first coated with crystals (black dots) with precision tip tweezers and a brushing tip to obtain a uniform layer. Photoresist (shown by the gray boxes) is then placed on top of the crystals and is spun at 5000 rpm for 30 s. Next, the sample is exposed to UV light wherever it is not blocked by the pattern mask (black rectangle). This defines the region where crystals are to remain. Finally, the sample is developed to remove the exposed regions.

moval of the crystals outside the desired area. To create a uniform layer of powder, a fine tip is brushed over the crystals while viewing under a microscope.

Next, a thick positive photoresist (AZ4620) is placed on top of the crystals and is spun at 5000 rpm for 30 s. This resist was chosen for two reasons. First, the layer must be thick enough to completely encapsulate the crystals of micron scale thickness. We have observed that in the case of micron sized crystals, other optical or electron-beam resists do not perform so well. Second, compared with other resists, this type of resist contains fewer solvents that could potentially be harmful to the crystals. In general, for an adequate choice of the resist, one should know as much as possible about the composition of the nanocrystal sample and avoid choosing resists that could dissolve or alter its structure. Following the spin coating process, the sample is placed immediately on a hot plate at 110 °C for 60 s to harden the resist and evaporate out any residual solvent. After the preexposure bake, the sample is cooled in a stream of nitrogen gas. Once cooled, the chip is exposed to ultraviolet light for about 4 s using a mask aligner, thus defining the pattern where the crystals are to be located. The sample is then immersed in the developer solution and agitated to remove the exposed photoresist regions (30-60 s). We noticed that in some cases it was necessary to place the sample in an ultrasonic bath during development in order to completely remove the crystals from the exposed region.

The method presented here was successfully tested for two different types of materials, as described below. Following each application, testing of the integrity of the spin environment was performed by ESR characterization. The ob-

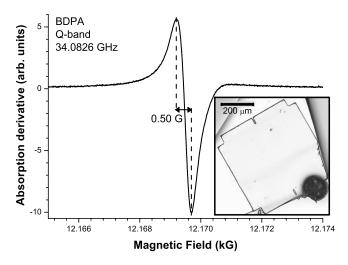


FIG. 2. Room temperature ESR measurement of one BDPA crystal entrapped in optical photoresist. The resonance width is 0.50 G, and the corresponding g-factor is 2.001. The insert shows an optical microscope image of the measured crystal (dark circle in lower right corner of the designed square box) as placed on a quartz glass. The crystal is entrapped in photoresist (the visible 500 micron box with corners cut out).

tained samples were measured at room temperature using a Bruker Elexsys-500 electron paramagnetic resonance setup operating at 34 GHz and using a standard TE_{011} cylindrical cavity. The optimization of the measured signal-to-noise microwave power and resolution was obtained by a proper adjustment of the field modulation, required to perform the derivative of the absorption curves shown in Figs. 2 and 3.

For a first application of the method, we entrapped a single crystal of BDPA on the surface of a quartz chip. BDPA has a known free radical concentration of 1.6×10^{19} g⁻¹ and a Zeeman factor g=2.0025. The derivative of the absorption curve measured at \sim 34 GHz is shown in Fig. 2. The signal is highly visible, indicating a typical resonance width of 0.50 G=0.050 mT and a g-factor g=hf/(μ_{BB})=2.001, where h is Planck's constant, μ_{B} is Bohr magneton, and f as the resonant frequency (see Fig. 2). These data show a non-destructive placement technique for a rather sensitive sample as the BDPA.

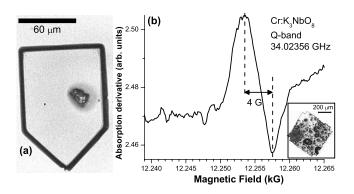


FIG. 3. (a) Photograph of a single crystal of $Cr: K_3NbO_8$ entrapped in the area delimited by the dark contour. The crystal is encased in optical photoresist, as shown by the gray surface of the contour. (b) Room temperature ESR measurement of diluted Cr^{5+} spins. The insert shows the actual sample, consisting of few tens of single crystals, in order to achieve a measurable signal by the Q-band spectrometer. The obtained signal is the result of 40 averages, as required by the small size of the signal.

The same entrapping technique was used to position a single crystal of Cr⁵⁺ spin 1/2 sample highly diluted in a potassium niobate nonmagnetic matrix (Cr: K₃NbO₈). The estimated concentration of spins is 0.03%, and the consequent number of spins in a single nanocrystal [see Fig. 3(a)] is below the spin sensitivity of the ESR setup used here. In order to perform the spin resonance study, another sample containing few tens of crystals was prepared [see the insert in Fig. 3(b)]. Due to the low spin concentration, we approached the limit of the measurement sensitivity, estimating the number of spins to be on the order of 10¹².

The derivative of the absorption spectra shows a small resonance signal (see Fig. 3) of width ΔB_{pp} =4 G corresponding to lifetime $T_2^* = 2\sqrt{2}/\Delta f = 250$ ns, with Δf = $f\Delta B_{pp}/B_{\rm res}$; f and $B_{\rm res}$ are the resonant frequency and field. This value of T_2^* agrees well with published data. The position of the resonance corresponds to a Zeeman factor g =1.9835, in agreement with the measured values for this quasi-isotropic crystal $(g_{\perp}=1.9878 \text{ and } g_{\parallel}=1.9472, \text{ from }$ Refs. 15 and 19). Note that in powder ESR, one generally observes a strong signal for g_{\perp} and a much smaller one for g_{\parallel} . In our case, the relatively large number of crystals explains the powderlike behavior of the signal, but the small number of spins makes detectable only the resonance corresponding to g_{\perp} . To ensure that the measured signal is due to Cr⁵⁺ and not to the photoresist encasing it, a bare photoresist sample on a quartz glass was measured and no interfering background signal was observed.

The presented crystal placement method can be applied to entrap any type of magnetic nanocrystal on a chip, such as the single molecule magnets or diamond samples containing NV color centers. Such magnetic objects have a small magnetic moment, making them inherently difficult to measure. Changes in spin orientation (i.e., $+1/2 \rightarrow -1/2$) will perturb only slightly the cavity, and therefore a high quality factor cavity is required. The Cr5+ spectrum shown in Fig. 3 actually shows that traditional cavity ESR has limited benefits when dealing with nanosized samples. The on-chip ESR technique holds the promise of increased sensitivity by using microstrip or superconducting cavities. Recent research has shown the ability to fabricate on-chip superconducting resonators with quality factors of 10^5-10^6 (Ref. 1) through the use of readily available standard photo or electron-beam lithography techniques. Their small size also allows the resonators to be easily incorporated with dilution refrigerators for millikelvin studies of spin-based qubits.

In conclusion, this technique shows the ability to nondestructively place magnetic microcrystals in a well defined location. Further plans for scaling down the entrapment region are being conducted with the requirement of a more sensitive measurement technique. Superconducting resonators are a promising means for attaining additional sensitivity as well as performing on-chip ESR studies at millikelvin temperatures. This research is necessary for determining the viability of micro-/nanocrystals and potentially molecular magnets as qubits for quantum computation.

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